Quantum uctuations in thin superconducting wires of nite length

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In one dimensional wires, uctuations destroy superconducting long-range order and sti ness at nite temperatures; in an in nite wire, quasi-long range order and sti ness survive at zero temperature if the wire's dimensionless admittance is large, > 2. We analyze the disappearance of this superconductor-insulator quantum phase transition in a nite wire and its resurrection due to the wire's coupling to its environment characterized through the dimensionless conductance K. Integrating overphase slips, we determ ine the own of couplings and establish the $\{K \text{ phase diagram}\}$.

In systems with reduced dimensions (Ims and wires) uctuations and disorder strongly in uence on the superconducting transition temperature [1], eventually driving a superconductor (insulator (SI) transition which has attracted a lot of attention recently [2, 3, 4]. In 1D wires, the uctuations of Cooper pairs appearing below the mean-eld transition at T_{c0} de ne a nite resistance via nucleation of thermally activated phase slips [5, 6] and hence rem ove the nite tem perature transition; superconductivity possibly survives only at zero tem perature. The focus then is on the quantum nucleation of phase slips; their proliferation may trigger a zero temperature SI quantum phase transition [7, 8, 9, 10]. While rst attempts to observe quantum phase slips [7] are still debated due to the granular structure of the wires [11, 12], recent experim ents on am orphous ultra-thin wires [3, 4] carry the signatures of a SI transition in a hom ogeneous system. In this letter, we analyze the bosonic Cooper pair uctuations in realistic wires of nite length which are naturally coupled to their environm ent through their boundaries; we demonstrate how the SI transition is quenched in the nite system and reappears through its coupling to the environm ent.

Previous studies of bosonic uctuations in in nite wires [9] have found a T = 0 SI quantum phase transition at the critical value = 2 of the dim ensionless adm ittance characterizing the wire's superconducting properties. At T > 0 the system exhibits a nite resistance; ignoring an additional dissipative channel due to excited quasi-particles, we call the non-superconducting state an insulating one. On the other hand, real experiments are carried out on wires of nite length, L 0:5 2 m typically [3]. The wire's coupling to the environment through appropriate boundary conditions in poses a drastic change in the phase slip dynamics and modies the wire's low-energy physics. A generic description is obtained by embedding the wire in a voltage driven loop with impedances Z_p (!) and Z_s (!) placed in parallel and in series, see Fig. 1. Here, we are mainly interested in therm odynam ic aspects (involving the static resistances R_p and R_s); furtherm ore we concentrate on the currentdriven limit with Rs R_p , then $I = V=R_s$ is xed. The voltage driven case with Rp R_s and other mixed cases (Rs of order Rp) are easily derived from the current-

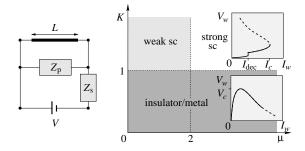


FIG. 1: Left: Setup with a quantum wire embedded in a voltage (V) driven loop with parallel (Z_p) and serial (Z_s) im pedances de ning the environm ent. Right: Phase diagram with superconducting and insulating phases separated by a quantum phase transition at K = 1. The superconducting phase splits into weak and strong regimes separated by a crossover at. 2, the leftover of the SI transition in the in nite wire. The insets show sketches of the wire's Iw-Vw characteristic at T = 0. In the superconductor (K > 1) the algebraic characteristic is dominated by the environment at sm all currents $I < I_{dec}$. A highly conducting shunt with allows to probe the wire above the decon nem ent current I_{dec} ; I_{c} denotes the critical current of the wire. The insulator exhibits a Coulomb gap behavior below the critical voltage V_c .

driven solution via K irchho 's laws, see below.

The coupling to the environm ent changes the T = 0 phase diagram of the in nite system, see Fig. 1: The SI transition at = 2 is turned into a crossover, while a new quantum phase transition appears at the critical value K = $R_{\rm Q}$ = $R_{\rm p}$ = 1 of the shunt's conductance ($R_{\rm Q}$ = h=2e² denotes the quantum resistance). A well conducting shunt with K > 1 relaxes the strain on the wire and produces a superconducting response with an algebraic I{V characteristic, while a low conductance K < 1 leads to the proliferation of phase slips and hence to an insulator. The characteristic response of the superconducting wire can be probed with a high conductance environm ent K at large drive above the current $I_{\rm dec}$ where con ned phase-slip pairs are separated.

In thin superconducting wires the plasma mode acquires a linear dispersion [13, 14] with sound velocity $c_{\rm s}$ (this contrasts with the bulk case where the Coulomb interaction lifts the plasma mode to nite frequencies).

The low frequency action describing the bosonic uctuations of the Cooper pairs then takes the form [8, 9, 10]

$$\frac{S_w}{h} = \frac{Z_h}{2} \int_0^{Z_{L=2}} dx c_s (\theta_x)^2 + \frac{1}{c_s} (\theta_x)^2 ; (1)$$

the rst (second) term accounts for the kinetic (com pression) energy (we assume a high energy cuto h= limiting the validity of (1)). Within a mean-eld description the dimensionless admittance and the sound velocity co are related to the 1D super uid density $s = n_s S = 2m$ and the Coulomb interaction between the Cooper pairs [9, 13], h $c_s=2 = h^2$ s=2 and h =2 $c_s = (h=2e)^2 C =2$ (here, S is the wire's cross section and $C = \ln (\hat{d} = S)$ is the capacitance per unit length, with the dielectric constant of the surrounding media placed a distance daway). With $_{L} = (4 \text{ n}_{\text{s}}\text{e}^2 = \text{mpc}^2)^{1-2}$ the London penetration $30^{\circ} \overline{\text{CS}} = \text{L} \text{ and } c_{\text{S}}^2 = c^2 \qquad 0.1 \text{S} = \frac{2}{1} \text{C}.$ length we obtain Going beyond the mean-eld level, both ferm ionic and bosonic high-energy uctuations play a critical role in the proper determ ination of the low-energy action [15]; here, we assume such elects to be included in our choice of e ective phenom enological param eters and c_s .

The coupling between the superconducting wire and the environment involves the boundary elds ()

(x;) $\dot{\mathbf{j}}_{=L=2}$ where (x;) = (x;) (x;): uctuations in the phase di erence generate a voltage V_w across the wire inducing currents in the parallel shunts, while uctuations in + account for charge accumulation. Here, we concentrate on the current-driven setup (see Fig. 1) described by the low-energy action

$$\frac{S_e}{h} = \frac{K}{2}^{Z} \frac{d!}{4} j! jj \quad (!)^2_J + \int_0^{Z_h} d \frac{I}{2e} ;$$
 (2)

with an ideal current source (R $_{\rm S}$ R $_{\rm p}$) driving the system with the current I and a parallel resistor with resistance R $_{\rm p}$ accounting for the dissipation (K = R $_{\rm Q}$ =R $_{\rm p}$ is the dimensionless conductance of the shunt). Protecting the system from the measurement setup using appropriate ltering [16], we can neglect capacitive e ects. The environment (2) does not account for an intrinsic, e.g., quasi-particle induced, dissipation in the superconducting wire; the latter contributes to the precise values of the parameters , c $_{\rm s}$, and (the vortex fugacity, see below).

The statistical mechanics of the system wire plus environment is determined by the partition function

$$Z = D[] exp[S()=h]$$
 (3)

with $S=S_w+S_e$. Its main contributions arise from the combination of Gaussian and topological uctuations, so-called phase slips or instantons. Gaussian uctuations destroy the superconducting long-range order as expressed by the logarithm ically diverging phase correlator h[(x;) $(x; ^0)$] 2 i K 1 ln j 0 j however,

the surviving quasi-long range order is su cient to allow for a nite phase sti ness, i.e., superconducting response. The latter is destroyed by the proliferation of phase slips, the process we are going to analyze in detail now.

Quantum phase slips are vortex-like solutions in x; space with nite winding (= 1) around a core region of size x_c g and c where the superconducting gap (x;) drops to zero; outside this core region they satisfy the di erential equation $[c_s^2 \theta_x^2 + \theta^2]$ (;x) = 0 within the wire and respect the boundary conditions

$$K j! j + c_s [0_x] = I=e;$$
 $[0_x]_+ = 0:$ (4)

The rst equation describes current conservation as given by K irchho 's law, with the supercurrent $I_w = (e c_s =)$ $[0_x]$ through the wire and the dissipative current $V_w = R_p$ in the shunt adding up to the total external current I (here, $[0_x]$) () $[0_x]$ (x;) $[0_x]$ and $[0_x]$ = hj! j =2e is the voltage over the wire). The second equation accounts for charge neutrality; we ignore additional capacitive contributions here. Note that Kirchho's law maintains the form (4) when going over to the general situation with impedances both in series and in parallel, $I_w + V_w = R_t = V = R_s$ w ith R_t $^1 = R_p$ $^1 + R_s$ 1 the total conductance and the total current $I = V = R_s$ is expressed through the driving voltage V . Hence once we know the solution V_w (I) R_Q I (I) to the current-driven problem (w ith R $_{p}$ = R), the solution I_{w} (V) $_{V}$ (V=R $_{Q}$) to the voltage-driven situation (with $R_s = R$) follows from the relation I K $_{\rm I}$ (I) = $_{\rm V}$ (I=K), with K = R $_{\rm O}$ =R.

The partition function (3) factorizes into G aussian and topological parts, Z = Z $_{\rm G}$ Z $_{\rm pop}$, where the latter can be expanded in a series Z $_{\rm top}$ = $^1_{\rm n=0}$ (n =n!) 2 Z $_{\rm n}$ (G) with

$$Z_{n} = \frac{Z Q_{2n} d_{m} d_{m} dx_{m}}{(c_{s}^{2})^{2n}} exp X_{if j} G(x_{i}; i; x_{j}; j)_{j}$$

The interaction G between vortex{anti-vortex pairs is the crucial quantity determ ining the system's behavior here we only quote the relevant results, see Ref. [17] for details. For the in nite wire, the interaction between vortices $k = \arg[(x + x) + ic_s(x)], k = 1;2$, is logarithm ic at all distances $\overline{x} = x_1 + x_2$, $\overline{x} = x_1 + x_2$,

G
$$(\overline{x}; \overline{}) = \ln[\overline{x}^2 = c_s^2 + \overline{}^2) = {}^2];$$
 (5)

A standard Kosterlitz{Thouless (KT) scaling analysis provides the RG equations [18] $e_1 = 4^2 2^2$ and

 $\theta_1=(2)$ (l is the scaling parameter) and the system undergoes a Berezinskii-K osterlitz-T houless transition [18] at =2. For >2, the number of free vortex{anti-vortex pairs is quenched and the wire is in the superconducting phase; for <2 the vortex fugacity increases and free vortex{anti-vortex pairs proliferate | the system turns insulating.

In a nite wire the solution has to respect the boundary condition (4). At low frequencies and vanishing drive these reduce to the Neum ann boundary conditions, θ_{x} (L=2;) = 0, i.e., the currents induced by phase slips cannot leave the wire. The solution $_{\scriptscriptstyle N}$ (x;) derives from the 2L-periodic solution 2L , using mirror vortices, $_{N}$ (x;) = $_{2L}$ $_{p}$ (x;)+ $_{2L}$ $_{p}$ (L x;); in turn, the instanton solution with periodic boundary conditions $_{\text{2L}}$ $_{\text{p}}$ (x;) = $_{\text{2L}}$ $_{\text{p}}$ (x + 2L;) derives from the solution in the in nite wire via conformal transformation. Fig. 2 illustrates the geometry of the phase slips; most rem arkably, at large distances the mutual screening of the defect-pair is replaced by the screening via in age charges. Hence the wire's contribution G_w to the action saturates at inter-vortex separations $\frac{1}{2}$ $\frac{1}{2}$ L= c_s, resulting in asymptotically free vortices. Furtherm ore, their action can be minimized by moving them to the boundary such that $G_w = 0$.

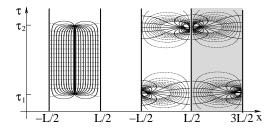


FIG. 2: Phase slip solutions with periodic (solid lines denote contours $_{\text{P}}$ = const; left) and Neum ann ($_{\text{N}}$, right) boundary conditions at intervortex distance L=c_{\text{S}}< - . Left: for K , defects are screened mutually, the 2 phase drop appears along the x-axis and drives a large current (dashed) through the highly conducting shunt; the resulting string connes defect pairs. Right: with K, defects are screened individually by their mirror im ages (grey underlaid), the 2 phase drop appears along the -axis and sets up displacement currents in the wire which cannot escape through shunt, hence charge accumulates at the boundary resulting in a large voltage over the shunt; the defects are asymptotically free.

In this situation the pair interaction is determined by the environment alone. Inserting the boundary eld $_{\mbox{\scriptsize N}}$ () describing two opposite kinks of shape 2 arctanfsinh[(g=L)($_{\mbox{\scriptsize k}}$)]= \cos ($x_{\mbox{\scriptsize k}}$ =L)g, k = 1;2, into the action (2) we obtain the contribution

$$G_{e}(x_{1}; x_{2}; \overline{})$$
 K $\ln \frac{\cos^{2} \frac{1}{2L}(x_{1} + x_{2}) + \frac{c_{s} - 2}{2L}}{\cos \frac{1}{L}x_{1} \cos \frac{1}{L}x_{2}}$ (6)

which diverges logarithm ically at long time scales, but with a weight determined by the dimensionless conduc-

tance K of the parallel shunt. In the end, the largest contribution to the partition function arises from vortices nucleated at the boundary with an interaction G $G_e = K \ln \Gamma^2 = 2$) and the problem maps to a system of charged particles in 1D with fugacity . The corresponding RG equations [19] take the form $\ell_1 K = 0$ and $\ell_1 = (1 - K)$; in contrast to the in nite wire, the prefactor K of the logarithm is invariant under the RG ow and we obtain a transition at K = 1 [20], with a superconducting phase for K > 1, while for K < 1 the vortices nucleated at the boundary drive the system insulating.

In the analysis above we have determ ined the shape of the vortex {anti-vortex pair assum ing N eum ann boundary conditions, i.e., no currents can leave the wire. Inserting this approxim ate solution back into (2) then has provided us with the pair-interaction G $G_e = 2K$ In $\Gamma = 1$. In order to check the consistency of this approximation we determ ine the correction S due to the nite current K I I owing through the shunt (cf. (4)),

$$\frac{S}{h} = \frac{K}{4} \frac{Z}{2} \frac{d!}{1 + (-K) \text{ joth (! L=2cs) j'}} (7)$$

with $_{\rm N}$ (4 =!) sin (! =2); perform ing the integral in (7) shows that the corrections are indeed small at low frequencies. For a setup with a poorly conducting shunt (K) the corrections remain small at higher energies when $^{-}$ < L= $_{\rm G}$, S (K= 2) ln ($^{-}$ =).

However, in the opposite case K where a highly conducting shunt protects the superconductor the corrections are large: in the intermediate regime $L=c_S<\overline{}<0$ tions are large: in the intermediate regime $L=c_S<\overline{}<0$ to C=0 the rst term cancels the logarithm is interaction with the environment, while the second term describes linearly con ned pairs. It is then appropriate to change strategy: for K and high frequencies the boundary condition (4) reduces to C=0 and C=0 and C=0 for C=0 and the phase—eld for the pair is given by the C=0 for C=0 and the producing an interaction between the vortices

describing defect pairs linearly con ned along the —axis for distances — > L= g, cf. Fig. 2. At the same time, no voltage appears over the shunt and the contribution from the environment vanishes, thus G $_{\rm p}$. Hence, for a highly conducting shunt K the interaction starts with a logarithm G (< L= g) $\ln [\Gamma^2 + \overline{x}^2] = ^2$], goes over into con nement G (L= c_s < — < $_{\rm B}$) 2 $_{\rm s}\overline{c}$ =L, and ends with the low-frequency behavior G ($_{\rm B}$ < —) K $\ln \Gamma^2 = ^2$) determined by the environment.

In the end, we nd that for all values of K the low-energy physics of the system is determined by the environment. On the other hand, the renormalization down to low energies depends on the ratio =K: for K the interaction is entirely determined by the

environm ent, while for K the phase-slip pairs go through an interm ediate regime of linear connement inducing an exponential drop of the phase-slip fugacity, ($_B$) ($_E$) exp[$_G$, ($_B$)] = ($_E$, exp($_B$)) = ($_E$, exp($_B$), this drop in manifests itself in the $_H$, enaracteristic. The above analysis results in a T = 0 phase diagram as sketched in Fig. 1: The transition at K = 1 separates a super uid phase for K > 1 from an insulating one at K < 1. In addition, we distinguish between two dierent superconducting regimes at K > 1: for < 2 the fugacity for the nucleation of small ($_H$ < L = $_G$) vortex (anti-vortex pairs is strongly increased as compared to the regime > 2, a leftover from the SI transition in the in-

W ith the interaction between defect pairs turning logarithm ic on large scales $^->{}_{\rm K}$ max(;_B), we not that the low-energy physics of the wire reduces to that of a Josephson junction with a parallel shunt R; the partition function is equivalent to that of a particle in a periodic potential with damping = K=2 [20]. The I{V-characteristic of such Josephson junctions has been studied in detail [20, 21]; below, we review the main results. The restricted validity of the elective action S=S_w+S_e to low energy scales \lim_{\to} its this analysis to low temperatures T < h= $_{\rm K}$ and low currents I < 2eK= $_{\rm K}$.

nite w ire w hich is relevant at tem peratures T > h $c_s = L$

and drives I > 2e $c_s = L$ probing these small scales.

W ithin the superconducting phase K > 1, the I characteristic at low drives I is calculated perturbatively in the vortex fugacity (w $i \pm h$ ($_{K}$)! the renormalized fugacity at $_{\rm K}$). At nite temperatures the two energy scales T and h I=2eK de netwo regimes in the response, V_{ps} (I=2eK T=h) ${}^{2}R_{O}I[T_{K}=h]^{2K}$ and (h 2 =e $_K$) [I $_K$ =e] 2K 1 ; the alge- V_{ps} (T=h I=2eK) braic characteristic at T = 0 tums into a linear response at nite T and small drives I. We conclude, that in 1D w ires superconductivity survives only at T = 0 and under the condition of a good protection by a high conductance shunt with K > 1. In addition, if Kcon nem ent in the regime c_s =L < $\overline{}$ < $_{\text{\tiny B}}$ produces a $(h^2=e)(L=c_s)[c_s=L]^2$ sharp voltage step V_{dec} at the decon $\,$ nem ent current $\rm I_{\rm dec}$ = $\,$ 2e $\,$ c $_{\! s} = \! L$. At highdrives I > I_{dec} (and at temperatures T > h c_s =L) we start probing the wire (i.e., intervortex distances - < g=L) and the I- V_w characteristic is given by the result for the in nite system [9], $\rm V_{ps}\,($ $\rm c_s=L$ < \rm I=2 e $(^{2}R_{Q}I)(L=c_{s})[T=h]^{2}$ and $V_{ps}(c_{s}=L<$ ($h^2 = e$) ($L = c_s$) [$I = e^{-\frac{2}{3}}$. The T = hI=2 e)wire's Iw Vw -characteristic derives from solution of the im plicit equation V_w (I_w) = V_{ps} ($I = I_w + V_w = R_p$).

In the insulating phase K < 1 the phase slips describe tunneling of the phase di erence — to neighboring states — 2 . In the lim it K ! 0 this tunneling between periodic minima is coherent and leads to the form ation of a B loch band "(q) of width W $_0 = h =$, with q the quasi-m omentum associated to — . Applying a small current I, a voltage $2\text{eV}_{\text{w}} = hh$ — i = Q_{q} "(q)

is set up across the wire and all the current ows over the parallel shunt [21]; the system exhibits a linear response $V_w=R$ I. This behavior remains valid for nite K < 1, but with a renormalized band width [16, 21, 22] W W_0 W_0 $_{\rm K}$ =h $_{\rm K}^{\rm K=(1-K)}$, dening a linear response regime for small voltages $2\text{eV}_{\rm w}<2\text{eV}_{\rm c}=\text{max}\left(\text{e}_{\rm q}\text{"}\right)$ W. At higher drives, the voltage $V_{\rm w}$ decreases as the phase slips no longer block the wire and the current ows across both channels.

The SI quantum phase transition in the nite wire is di erent from the one in the in nite system; it is of the type inherent to nite systems coupled to a dissipative environm ent, e.g., the resistively shunted Josephson junction [20] or the dissipative two-state system [23]. The environm ent determ ines the wire's therm odynamic state and hence the overall shape of the I_w { V_w -characteristic, see Fig. 1; the wire's parameters and make their appearance (through the voltage jump at Idec and the w ire-dom inated characteristic at large currents $I > I_{dec}$) only in the superconducting phase K > 1 and for the where a highly conducting shunt is protecting the wire. The insulating phase is established at sm all values K < 1; phase-slips drive the current over the parallel shunt, resulting in an ohm ic characteristic, until leakage through the wire sets in at V_c. Here, we have assum ed a sm allvortex fugacity and hence the observation (and consistent interpretation) of the characteristic voltage-peak requires a sensitive probe as V_c / $^{1=(1-K)}$.

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